

Amendments to the Specification

On page 1, after the title "Transistor and Semiconductor Device" please insert the following paragraph:

- - This application is a divisional of US patent application 09/850,732, ^{now US Patent 6,727,522,} which is a U.S. national stage application of international application PCT/JP99/06300 filed November 11, 1999, which claims the benefit of Japanese application 10-326889, filed November 17, 1998.

The disclosure of application No. 09/850,732 is incorporated herewith by reference.--

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11/10/99